

02/04/03

RELIABILITY REPORT FOR

DS21349, Rev B1

Dallas Semiconductor

4401 South Beltwood Parkway Dallas, TX 75244-3292

Prepared by:

Ken Wendel

Ken Wendel Reliability Engineering Manager Dallas Semiconductor 4401 South Beltwood Pkwy. Dallas, TX 75244-3292 Email : ken.wendel@dalsemi.com ph: 972-371-3726 fax: 972-371-6016 mbl: 214-435-6610

Conclusion:

The following qualification successfully meets the quality and reliability standards required of all Dallas Semiconductor products and processes:

DS21349, Rev B1

In addition, Dallas Semiconductor's continuous reliability monitor program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards. The current status of the reliability monitor program can be viewed at http://www.maxim-ic.com/TechSupport /dsreliability.html.

Device Description:

A description of this device can be found in the product data sheet. You can find the product data sheet at http://dbserv.maxim-ic.com/l_datasheet3.cfm.

Reliability Derating:

The Arrhenius model will be used to determine the acceleration factor for failure mechanisms that are temperature accelerated.

AfT = exp((Ea/k)*(1/Tu - 1/Ts)) = tu/ts AfT = Acceleration factor due to Temperature tu = Time at use temperature (e.g. 55°C) ts = Time at stress temperature (e.g. 125°C) k = Boltzmann's Constant (8.617 x 10-5 eV/°K) Tu = Temperature at Use (°K) Ts = Temperature at Stress (°K) Ea = Activation Energy (e.g. 0.7 ev)

The activation energy of the failure mechanism is derived from either internal studies or industry accepted standards, or activation energy of 0.7ev will be used whenever actual failure mechanisms or their activation energies are unknown. All deratings will be done from the stress ambient temperature to the use ambient temperature.

An exponential model will be used to determine the acceleration factor for failure mechanisms, which are voltage accelerated.

AfV = exp(B*(Vs - Vu)) AfV = Acceleration factor due to Voltage Vs = Stress Voltage (e.g. 7.0 volts) Vu = Maximum Operating Voltage (e.g. 5.5 volts) B = Constant related to failure mechanism type (e.g. 1.0, 2.4, 2.7, etc.)

The Constant, B, related to the failure mechanism is derived from either internal studies or industry accepted standards, or a B of 1.0 will be used whenever actual failure mechanisms or their B are unknown. All deratings will be done from the stress voltage to the maximum operating voltage. Failure rate data from the operating life test is reported using a Chi-Squared statistical model at the 60% or 90% confidence level (Cf).

The failure rate, Fr, is related to the acceleration during life test by:

 $\label{eq:Fr} \begin{array}{l} \mathsf{Fr} = \mathsf{X}/(\mathsf{ts} * \mathsf{A}\mathsf{f}\mathsf{V} * \mathsf{A}\mathsf{f}\mathsf{T} * \mathsf{N} * 2) \\ \mathsf{X} = \mathsf{Chi-Sq} \text{ statistical upper limit} \\ \mathsf{N} = \mathsf{Life} \text{ test sample size} \end{array}$

Failure Rates are reported in FITs (Failures in Time) or MTTF (Mean Time To Failure). The FIT rate is related to MTTF by:

MTTF = 1/Fr

NOTE: MTTF is frequently used interchangeably with MTBF.

The calculated failure rate for this device/process is:

| FAILURE RATE: | MTTF (YRS): 1737 | FITS: 65.7 |
|---------------|------------------|------------|
| | | |

The parameters used to calculate this failure rate are as follows:

| Cf: 60% | Ea: 0.7 | B: 0 | Tu: 25 °C | Vu: 3.3 Volts |
|---------|---------|------|-----------|---------------|
|---------|---------|------|-----------|---------------|

The reliability data follows. A the start of this data is the device information. This is a description of the device either used as a reliability test vehicle for a process / assembly qualification / monitor or a device used as part of a product qualification / monitor. Following this is the assembly information. This section includes a description of the assembly vehicle used to generate this reliability data for both qualification / monitor. The next section is the detailed reliability data for each stress found in the qualification / monitor. If there are additional processes or assemblies used as part of this report, a description of each will follow which includes the respective reliability data for that process/ assembly. The reliability data section includes the latest data available.

| Device Information | n: | | | | | |
|---|---|--|-----|---------|----------|-------|
| Device: Process: Passivation: Die Size: Number of Trans | istors: | DS21349 D6H-2P2M,HPVt,TCZ_PBL:GOI Laser/TEOS Ox - Pass/Nit - Gen.LaserF 185 x 209 | Ŷrb | | | |
| Interconnect: Gate Oxide Thick | mess: | Aluminum / 1% Silicon / 0.5% Copper 150 Å | | | | |
| Assembly Information | tion: | | | | | |
| Qualification Veh | icle: | DS21349 | | | | |
| Assembly Site: | | ATP (Amkor, PI) | | | | |
| Pin Count: | | 28 | | | | |
| Package Type: | Package Type: PLCC | | | | | |
| Body Size: | | 450x450x3.9 | | | | |
| Mold Compound: Nitto MP8000C | | | | | | |
| Lead Frame: | Lead Frame: Stamped Copper CDA151 | | | | | |
| Lead Finsh: | finsh: SnPb Plate | | | | | |
| Die Attach: | Die Attach: 8361J Epoxy Silverfilled Ablebond | | | | | |
| Bond Wire / Size: | : | Au / 1.0 mil | | | | |
| Flammability: | | UL 94-V0 | | | | |
| Moisture Sensitiv | | Level 1 | | | | |
| (JEDEC J-STD | 20A) | | | | | |
| Date Code Range | e: | 0241 to 0241 | | | | |
| ELECTRICAL CHAR | ACTERIZA | TION | | | | |
| DESCRIPTION | DATE C | ODE CONDITION | RE | ADPOINT | QUANTITY | FAILS |
| ESD SENSITIVITY | 0241 | EOS/ESD S5.1 HBM 500 VOLTS | 1 | PULSES | S 3 | 0 |
| ESD SENSITIVITY | 0241 | EOS/ESD S5.1 HBM 1000 VOLTS | 1 | PULSES | S 3 | 0 |
| | | | | | | |

| HIGH TEMPERATURE OPERATING LIFE | | | | | | |
|---------------------------------|------|-----------------------------|---|--------|---|---|
| | | | | Total: | | 3 |
| LATCH-UP | 0241 | JESD78, Vsupply TEST 125C | | | 6 | 0 |
| LATCH-UP | 0241 | JESD78, I-TEST 125C | | | 6 | 0 |
| ESD SENSITIVITY | 0241 | EOS/ESD S5.1 HBM 8000 VOLTS | 1 | PULSES | 3 | 3 |
| ESD SENSITIVITY | 0241 | EOS/ESD S5.1 HBM 2000 VOLTS | 1 | PULSES | 3 | 0 |

| DESCRIPTION | DATE CODE | CONDITION | | REA | DPOINT | QUANTITY | FAILS |
|-------------------|-----------|-----------------|-------|------|---------------|----------|-------|
| HIGH VOLTAGE LIFE | 0241 | 125C, 6.0 VOLTS | | 192 | HOURS Tota | | 0 |
| FAILURE RATE: | МТТ | F (YRS): 1737 | FITS: | 65.7 | 100 | | Ū |